

RF AMPLIFIER

MODEL *TM3022*

Available as: TM3022, 4 Pin TO-8 (T4)
 TN3022, 4 Pin Surface Mount (SM3)
 FP3022, 4 Pin Flatpack (FP4)
 BX3022, Connectorized Housing (H1)

Features

- High Gain: 21 dB Typical
- Output Power: +13 dBm Typical
- Operating Temp. - 55 °C to + 85 °C
- Environmental Screening Available

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	700 - 1300 MHz	700 - 1300 MHz
Gain (dB)	21.0	19.0 Min.
Power @ 1 dB Comp. (dBm)	+13	+11 Min.
Reverse Isolation (dB)	-35	-33 Max.
VSWR In	<1.75:1	2.0:1 Max.
Out	<1.75:1	2.0:1 Max.
Noise Figure (dB)	<3.5	4.0 Max.
Power Vdc	+15	+15
mA	65	70 Max.

Note: Care should always be taken to effectively ground the case of each unit.

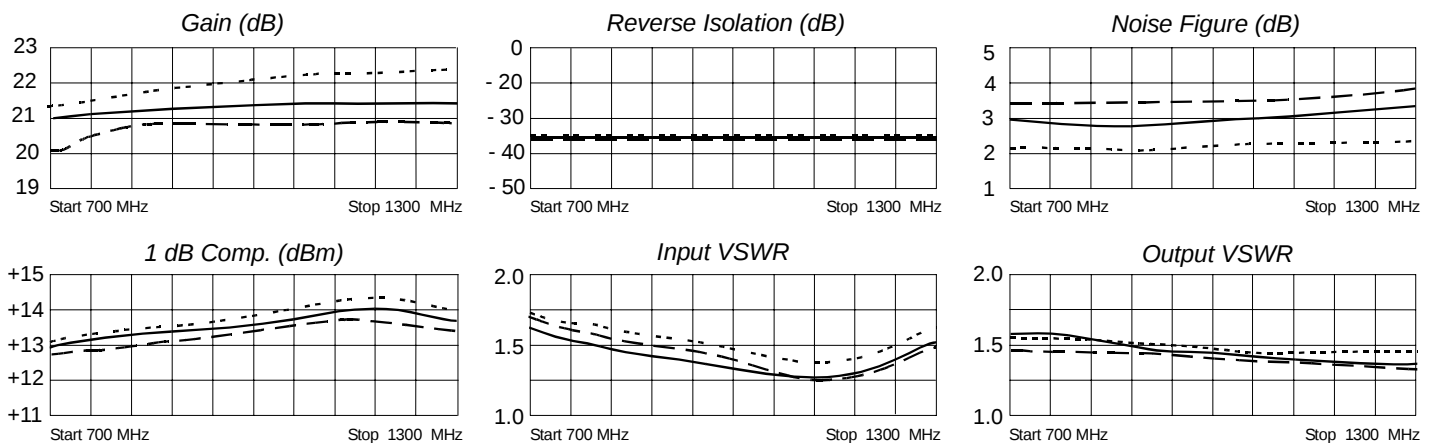
Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point..... +38 dBm (Typ.)
 Second Order Two Tone Intercept Point..... +32 dBm (Typ.)
 Third Order Two Tone Intercept Point..... +23 dBm (Typ.)

Maximum Ratings

Ambient Operating Temperature -55°C to + 100 °C
 Storage Temperature -62°C to + 125 °C
 Case Temperature + 125 °C
 DC Voltage + 18 Volts
 Continuous RF Input Power + 13 dBm
 Short Term RF Input Power 50 Milliwatts (1 Minute Max.)
 Maximum Peak Power 0.5 Watt (3 µsec Max.)

Typical Performance Data



Legend ——— + 25 °C - - - + 85 °C -55 °C